

**IN THE CLAIMS:**

1. - 2. (Canceled)

3. (Currently Amended) ~~The high frequency receiver (1) according to claim 2~~ A high frequency receiver (1), which is provided with a front end comprising a low noise amplifier (2), and which is provided with quadrature mixers (3) coupled to the low noise amplifier (2), characterised in that the low noise amplifier is a quadrature low noise amplifier (2-1, 2-2), characterised in that quadrature paths (I, Q) of the quadrature low noise amplifier (2-1, 2-2) are implemented differentially.

4. (Original) The high frequency receiver (1) according to claim 3, characterised in that the differential quadrature low noise amplifier (2-1; 2-2) is constructed as a class AB operating circuit.

5. (Currently Amended) The high frequency receiver (1) according to claim 3~~2~~, ~~characterised in that~~ wherein the quadrature low noise amplifier (2-1, 2-2) comprises a cascode arrangement of semiconductors (15).

6. (Currently Amended) The high frequency receiver (1) according to claim 5, ~~characterised in that~~ wherein the semiconductors (15) are of the type MOST, ~~such as NMOST or PMOST, or FET, or the like.~~

7. (Currently Amended) ~~The high frequency receiver (1) according to claim 5~~A high frequency receiver (1), which is provided with a front end comprising a low noise amplifier (2), and which is provided with quadrature mixers (3) coupled to the low noise amplifier (2), characterised in that the low noise amplifier is a quadrature low noise amplifier (2-1, 2-2), in that the quadrature low noise amplifier (2-1, 2-2) comprises a cascode arrangement of semiconductors (15), characterised and in that across the cascode arrangement of semiconductors (15) there is connected a capacitor (C).

8. (Currently Amended) ~~The high frequency receiver (1) according to claim 2~~A high frequency receiver (1), which is provided with a front end comprising a low noise amplifier (2), and which is provided with quadrature mixers (3) coupled to the low noise amplifier (2), characterised in that the low noise amplifier is a quadrature low noise amplifier (2-1, 2-2), characterised in that the high frequency receiver (1) comprises two quadrature choppers (10-1, 10-2) coupled between respective outputs (4, 5) of the quadrature low noise amplifiers (2-1, 2-2) and respective inputs of the quadrature mixers (3-1, 3-2).

9. (Currently Amended) The high frequency receiver (1) according to claim 8,  
~~characterised in that~~wherein the quadrature choppers (10-1, 10-2) and quadrature mixers (3-1, 3-2) are combined to passive quadrature choppers/mixers.

10. (Cancelled)

11. (Currently Amended) A quadrature low noise amplifier ~~(2-1, 2-2)~~ for application in the high frequency receiver (1) according to claim 32.

12. (New) A method for receiving high frequency signals, comprising:

implementing, differentially, quadrature paths of a quadrature low noise amplifier disposed at a front end of a high-frequency receiver; and  
coupling quadrature mixers to the amplifier.

13. (New) The method of claim 3, wherein the differential quadrature low noise amplifier is constructed as a class AB operating circuit.

14. (New) The method of claim 3, wherein the quadrature low noise amplifier comprises a cascode arrangement of semiconductors.

15. (New) The method of claim 5, wherein the semiconductors are of the type MOST.